ZXCT1008

HIGH-SIDE CURRENT MONITOR

Description

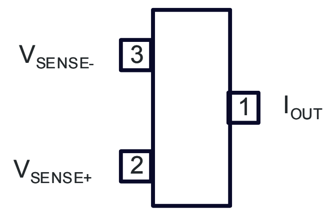
The ZXCT1008 is a high side current sense monitor. Using this device eliminates the need to disrupt the ground plane when sensing a load current.

It takes a high side voltage developed across a current shunt resistor and translates it into a proportional output current. A user defined output resistor scales the output current into a ground-referenced voltage.

The wide input voltage range of 20V down to as low as 2.5V make it suitable for a range of applications. The ability to withstand high voltage transients and reverse polarity connection makes this part very suitable for automotive and other transient rich environment.

Pin Assignments

SOT23
Package Suffix - F



(Top View)

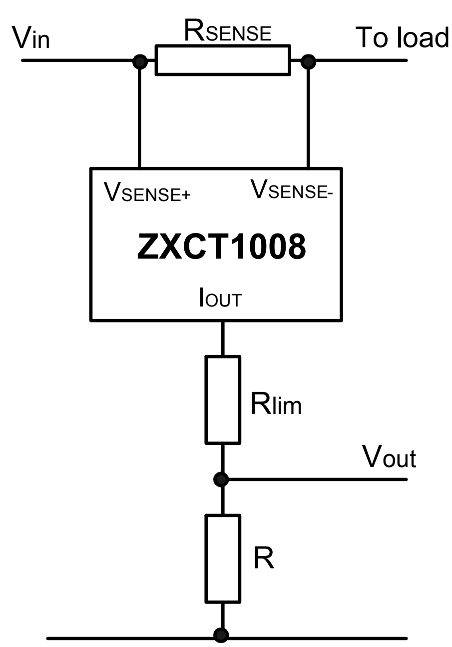
Features

- Low cost, accurate high-side current sensing
- -40 to +125°C temperature range
- Up to 500mV sense voltage
- 2.5V to 20V supply range
- 4μA quiescent current
- 1% typical accuracy
- SOT23
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q100 Standards for High Reliability**

Applications

- Automotive current measurement
- DC motor and solenoid control
- Over current monitor
- Power management

Application Circuit



Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Descriptions

Pin Name	Pin Function
V_{SENSE+}	Connection to supply voltage
V_{SENSE-}	Connection to load
I_{OUT}	Output current, proportional to measured current

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Description		Rating	Unit
Voltage on any pin (relative to I_{OUT})		-0.6 to 20	V
Continous output current, I_{OUT}		25	mA
Continuous sense voltage, V_{SENSE} †		-0.5 to +5	V
Operating temperature, T_A		-40 to +85	°C
Storage temperature		-55 to +125	°C
Package power dissipation @ T_A = +25°C (Derate to zero @ +125°C)	SOT23	450	mW
	SM8	2	W

Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings for extended periods may reduce device reliability.

Electrical Characteristics (@T_A = +25°C, V_{IN} = 5V, R_{OUT} = 100Ω, unless otherwise specified.)

Symbol	Parameter	Conditions	Limits			Units
			Min	Typ	Max	
V_{IN}	V_{CC} range	–	2.5	–	20	V
I_{OUT} [1]	Output Current	V_{SENSE} = 0V V_{SENSE} = 10mV V_{SENSE} = 100mV V_{SENSE} = 200mV V_{SENSE} = 500mV	1 90 0.975 1.95 4.8	4 104 1.0 2.0 5.0	15 120 1.025 2.05 5.2	μA μA mA mA mA
V_{SENSE} †	Sense Voltage	–	0	–	500	mV
I_{SENSE-}	V_{SENSE-} Input Current	–	–	–	100	nA
A_{CC}	Accuracy	R_{SENSE} = 0.1Ω V_{SENSE} = 200mV	-2.5	–	2.5	%
G_M	Transconductance, I_{OUT}/V_{SENSE}	–	–	10000	–	μA/V
BW	Bandwidth	$V_{SENSE(DC)}$ = 10mv, RF P_{IN} = -40dBm‡ $V_{SENSE(DC)}$ = 100mv, RF P_{IN} = -20dBm‡	– –	300 2	– –	kHz MHz

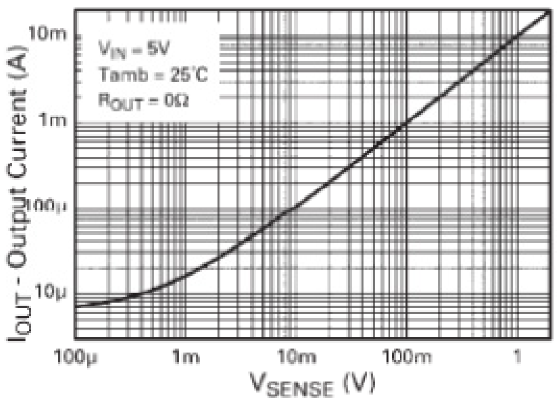
Notes: 4. Includes input offset voltage contribution

†. V_{SENSE} is defined as the differential voltage between V_{SENSE+} and V_{SENSE-}.

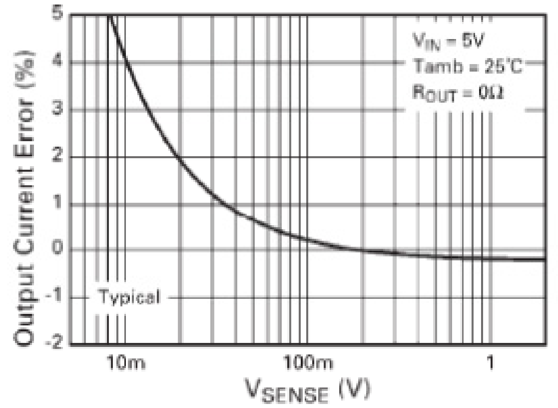
$V_{SENSE} = V_{SENSE+} - V_{SENSE-}$
$= V_{IN} - V_{LOAD}$
$= I_{LOAD} \times R_{SENSE}$

‡ -20dBm=63mVpp into 50Ω

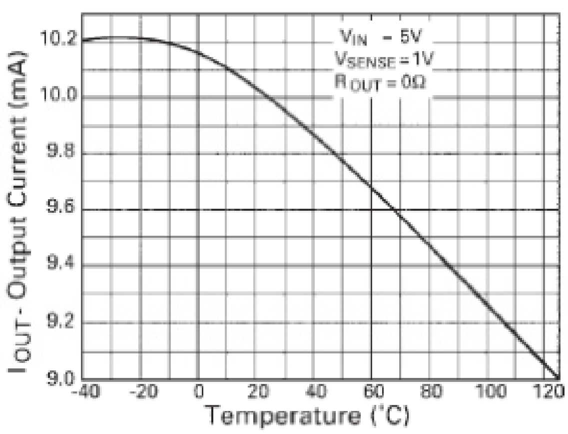
Typical Characteristics



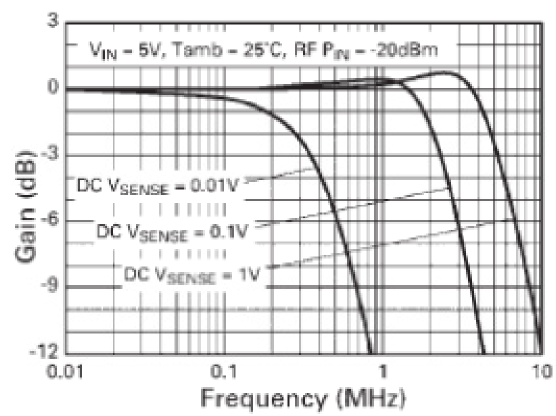
Typical Output v Sense Voltage



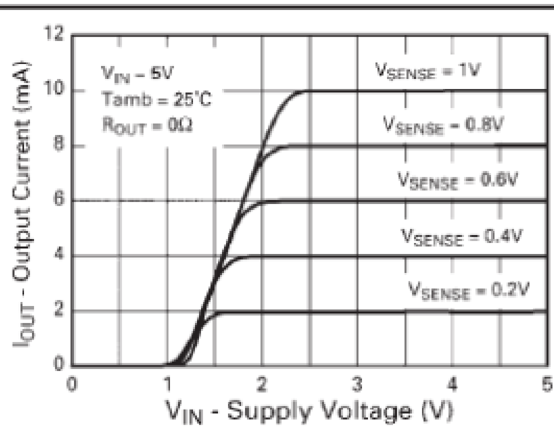
Error v Sense Voltage



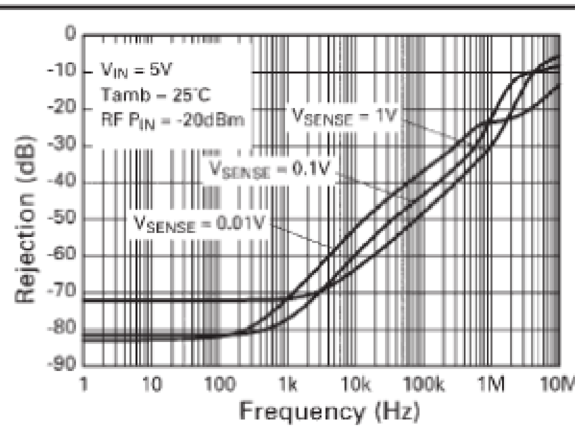
Output Current Temperature



Frequency Response

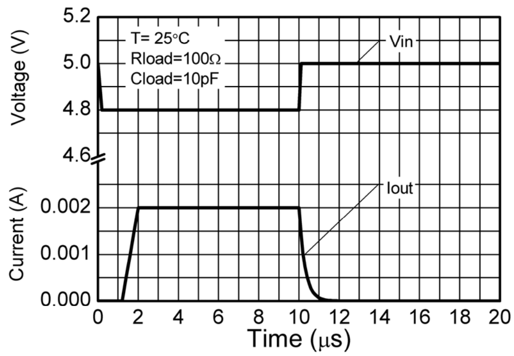


Transfer Characteristic



Common Mode Rejection

Typical Characteristics (cont.)



Step Response

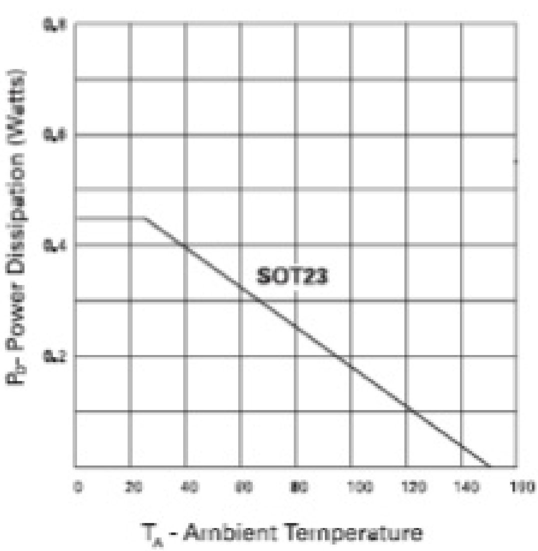
Power Dissipation

The maximum allowable power dissipation of the device for normal operation (P_{MAX}), is a function of the package junction to ambient thermal resistance (θ_{JA}), maximum junction temperature (T_{JMAX}), and ambient temperature (T_{AMB}), according to the expression:

$P_{MAX} = (T_{JMAX} – T_{AMB}) / \theta_{JA}$

The device power dissipation, P_D is given by the expression:

$P_D = I_{OUT}(V_{IN} - V_{OUT})$ W



Application Information

The following text describes how to scale a load current to an output voltage.

$V_{SENSE} = V_{IN} - V_{LOAD}$
$V_{OUT} = 0.01 \times V_{SENSE} \times R_{OUT}$ [1]

E.g.

A 1A current is to be represented by a 100mV output voltage:

1) Choose the value of R_{SENSE} to give 50mV > V_{SENSE} > 500mV at full load.

For example V_{SENSE} = 100mV at 1.0A.

R_{SENSE} = 0.1/1.0 => 0.1Ω.

2) Choose R_{OUT} to give V_{OUT} = 100mV, when V_{SENSE} = 100mV.

Rearranging [1] for Rout gives:

$R_{OUT} = V_{OUT} / (V_{SENSE} \times 0.01)$
$R_{OUT} = 0.1 / (0.1 \times 0.01) = 100\Omega$

Application Information (cont.)

Where R_{LOAD} represents any load including DC motors, a charging battery or further circuitry that requires monitoring, R_{SENSE} can be selected on specific requirements of accuracy, size and power rating.

An additional resistor, R_{LIM} can be added in series with R_{OUT} (as below), to limit the current from I_{OUT}. Any circuit connected to V_{OUT} will be protected from input voltage transients. This can be of particular use in automotive applications where load dump and other common transients need to be considered. The Zener Z1 provides additional protection for local dump, reverse battery and high voltage transient incidents.

Assuming the worst case condition of V_{OUT} = 0V; providing a low impedance to a transient, the minimum value of R_{LIM} is given by:

$$R_{LIM(min)} = (V_{PK} - V_{MAX})/I_{PK}$$

V_{PK} = Peak transient voltage to be withstood
V_{MAX} = Maximum working voltage = 20V
I_{PK} = Peak output current = 40mA

The maximum value of R_{LIM} is set by $V_{IN(MIN)}$, $V_{OUT(MAX)}$ and the dropout voltage (see transfer characteristic on page 3) of the ZXCT1008:

$$R_{LIM(MAX)} = R_{OUT}[V_{IN(MIN)} - (V_{DP} + V_{OUT(MAX)})]/V_{OUT(MAX)}$$

$V_{IN(MIN)}$ = Minimum Supply Operating Voltage
V_{DP} = Dropout Voltage
$V_{OUT(MAX)}$ = Maximum Operating Output Voltage

Typical Automotive Circuit Application

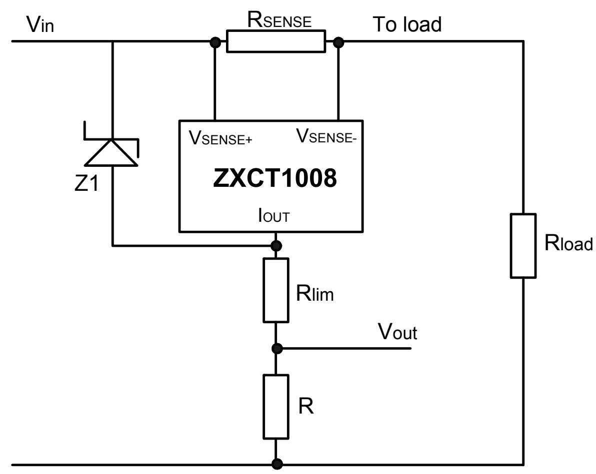


Figure 1.0

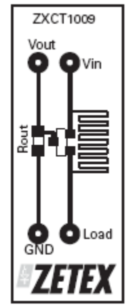
ZXCT1008 with additional current limiting Resistor R_{LIM} and Zener Z1.

Application Information (cont.)

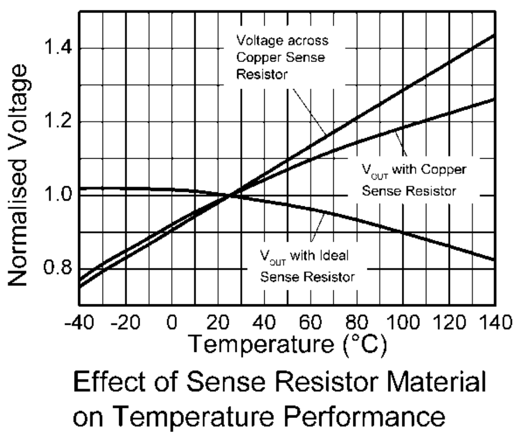
PCB trace shunt resistor for low cost solution

The figure below shows output characteristics of the device when using a PCB resistive trace for a low cost solution in replacement for a conventional shunt resistor. The graph shows the linear rise in voltage across the resistor due to the PTC of the material and demonstrates how this rise in resistance value over temperature compensates for the NTC of the device.

The figure opposite shows a PCB layout suggestion. The resistor section is 25mm x 0.25mm giving approximately 150mΩ using 1oz copper. The data for the normalized graph was obtained using a 1A load current and a 100Ω output resistor. An electronic version of the PCB layout is available through Diodes applications group.



Layout shows area of shunt resistor compared to SOT23 package. Not actual size.



Effect of Sense Resisitor Material on Temperature Performance

Ordering Information

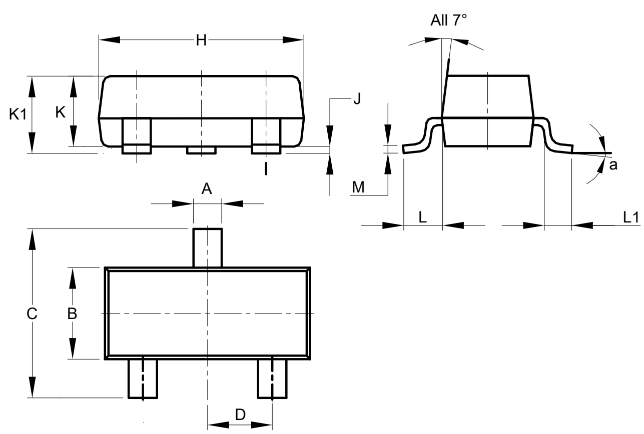
Device	AEC-Q100 level	Reel Size	Tape Width	Quantity per Reel	Part Marking	Package
ZXCT1008FTA	Grade 3	7”	8mm	3000 Units	108	SOT23
ZXCT1008F-7	None	7”	8mm	3000 Units	108	SOT23

Note: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf

Package Outline Dimensions (All dimensions in mm.)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

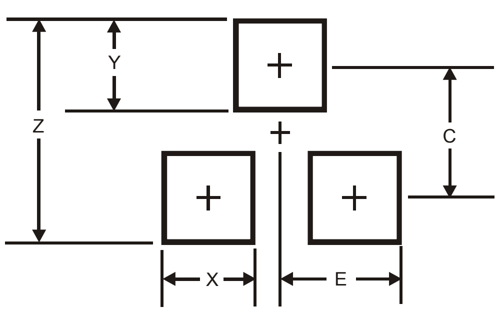
1) SOT23



SOT23			
Dim	**Min**	**Max**	**Typ**
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	8°		
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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